

## Features

- 350Watts peak pulse power ( $t_p = 8/20\mu s$ )
- Unidirectional configurations
- Solid-state silicon-avalanche technology
- Low clamping voltage
- Low leakage current
- Protection one data/power line to:
- IEC 61000-4-2  $\pm 25kV$  contact  $\pm 25kV$  air
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- IEC 61000-4-5 (Lightning) 5A (8/20 $\mu s$ )



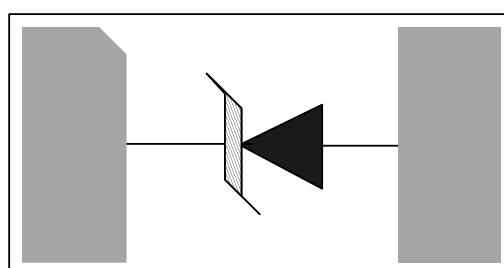
## Applications

- Microprocessor based equipment
- Personal Digital Assistants (PDA's)
- Notebooks, Desktops, and Servers
- Portable Instrumentation

## Mechanical Data

- DFN1006 package
- Molding compound flammability rating: UL 94V-0
- Packaging: Tape and Reel
- RoHS/WEEE Compliant

## Schematic & PIN Configuration



DFN1006



**Absolute Maximum Rating**

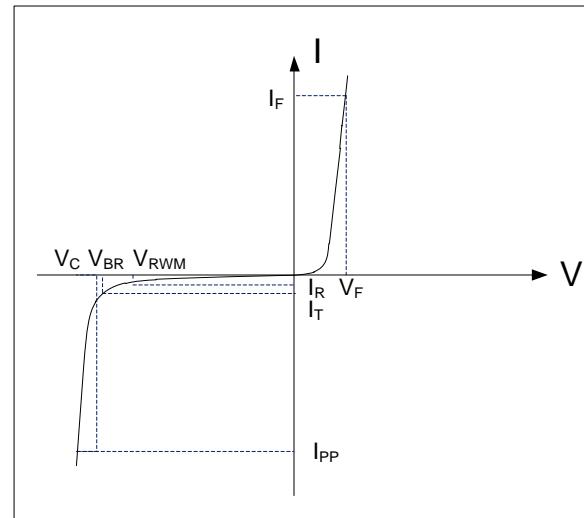
Rating	Symbol	Value	Units
Peak Pulse Power ( $t_p = 8/20\mu s$ )	P <sub>PP</sub>	350	Watts
Peak Pulse Current ( $t_p = 8/20\mu s$ ) (note1)	I <sub>PP</sub>	5	A
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	V <sub>ESD</sub>	25 25	kV
Lead Soldering Temperature	T <sub>L</sub>	260(10seconds)	°C
Junction Temperature	T <sub>J</sub>	-55 to + 125	°C
Storage Temperature	T <sub>stg</sub>	-55 to + 125	°C

**Electrical Characteristics**

Parameter	Symbol	Conditions	Min	Typical	Max	Units
Reverse Stand-Off Voltage	V <sub>RWM</sub>				36	V
Reverse Breakdown Voltage	V <sub>BR</sub>	I <sub>T</sub> =1mA	40			V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> =36V,T=25°C			0.5	µA
Peak Pulse Current	I <sub>PP</sub>	tp =8/20µs		5		A
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> =5A,t <sub>p</sub> =8/20µs			70	V
Junction Capacitance	C <sub>j</sub>	V <sub>R</sub> = 0V, f = 1MHz		30		pF

**Electrical Parameters (TA = 25°C unless otherwise noted)**

Symbol	Parameter
I <sub>PP</sub>	Maximum Reverse Peak Pulse Current
V <sub>C</sub>	Clamping Voltage @ I <sub>PP</sub>
V <sub>RWM</sub>	Working Peak Reverse Voltage
I <sub>R</sub>	Maximum Reverse Leakage Current @ V <sub>RWM</sub>
V <sub>BR</sub>	Breakdown Voltage @ I <sub>T</sub>
I <sub>T</sub>	Test Current

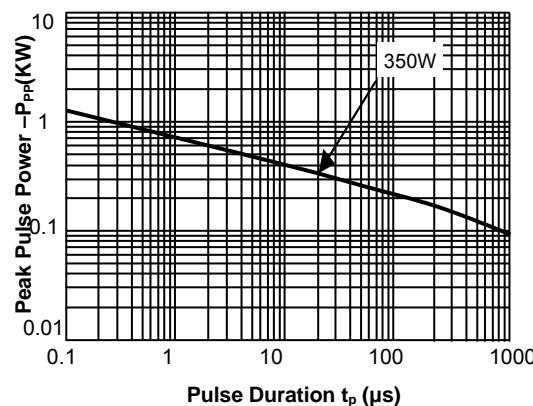


Note.: 8/20µs pulse waveform.

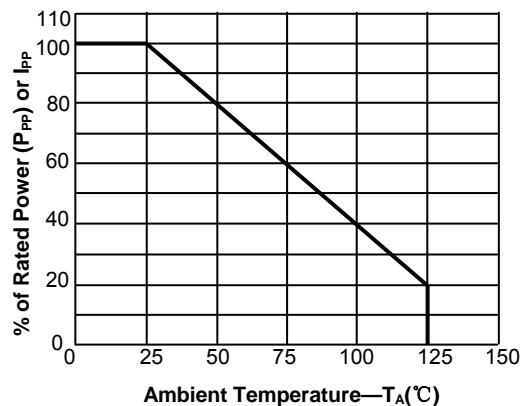


## Typical Characteristic

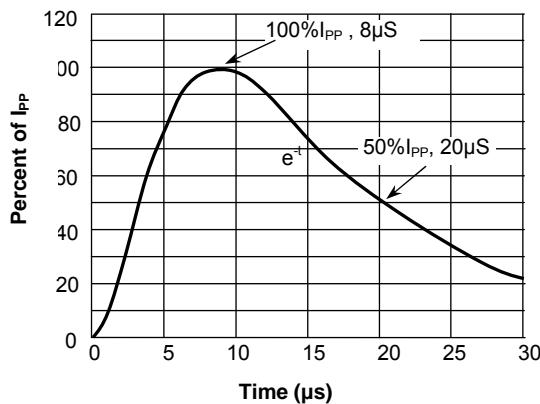
**Fig.1 Peak Pulse Power Rating Curve**



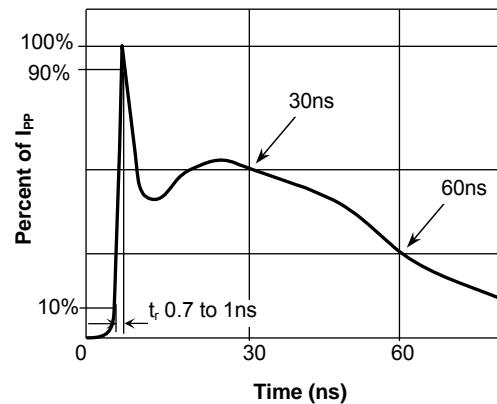
**Fig.2 Pulse Derating Curve**



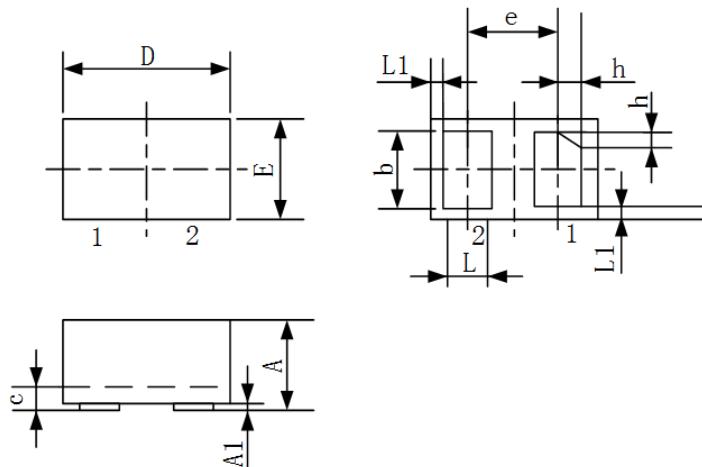
**Fig.3 Pulse Waveform-8/20 $\mu\text{s}$**



**Fig.4 Pulse Waveform-ESD(IEC61000-4-2)**



## Outline Drawing – DFN1006



SYMBOL	MILLIMETER		
	MIN	NOM	MAX
A	0.40	0.50	0.55
A1	0	0.02	0.05
b	0.45	0.50	0.55
c	0.12	0.15	0.18
D	0.95	1.00	1.05
e	0.65BSC		
E	0.55	0.60	0.65
L	0.20	0.25	0.30
L1	0.05REF		
h	0.07	0.12	0.17
载体尺寸 (MIL)	20*20		

## Marking



## Ordering information

Order code	Package	Base qty	Delivery mode
RLSD92Q361V	DFN1006	10k	Tape and reel

